

LCD WITH INCREASED PIXEL
OPENING SIZES

Filed: January 23, 2002

Attorney Docket No. 8733.215.20

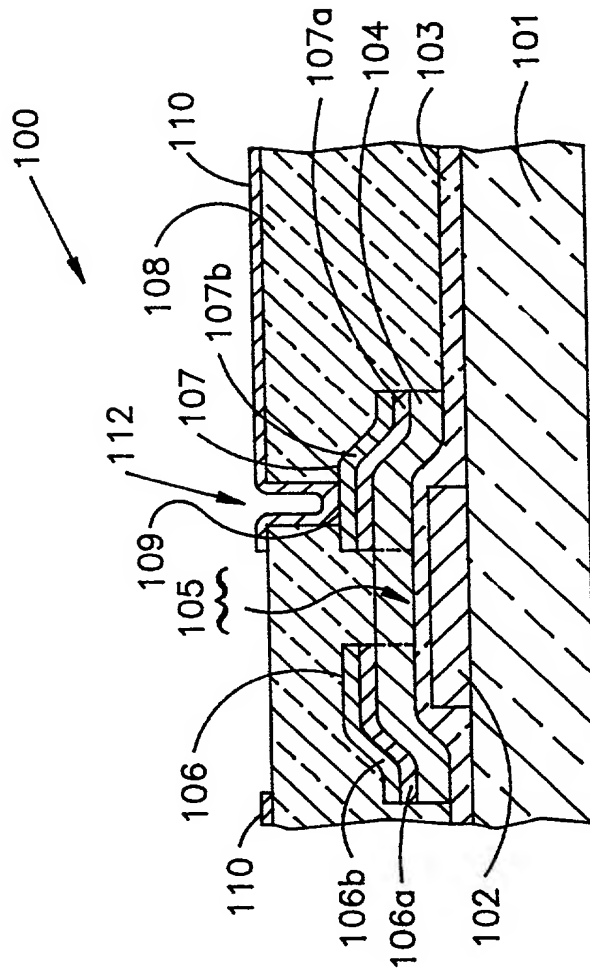


FIG. 1
(Prior Art)

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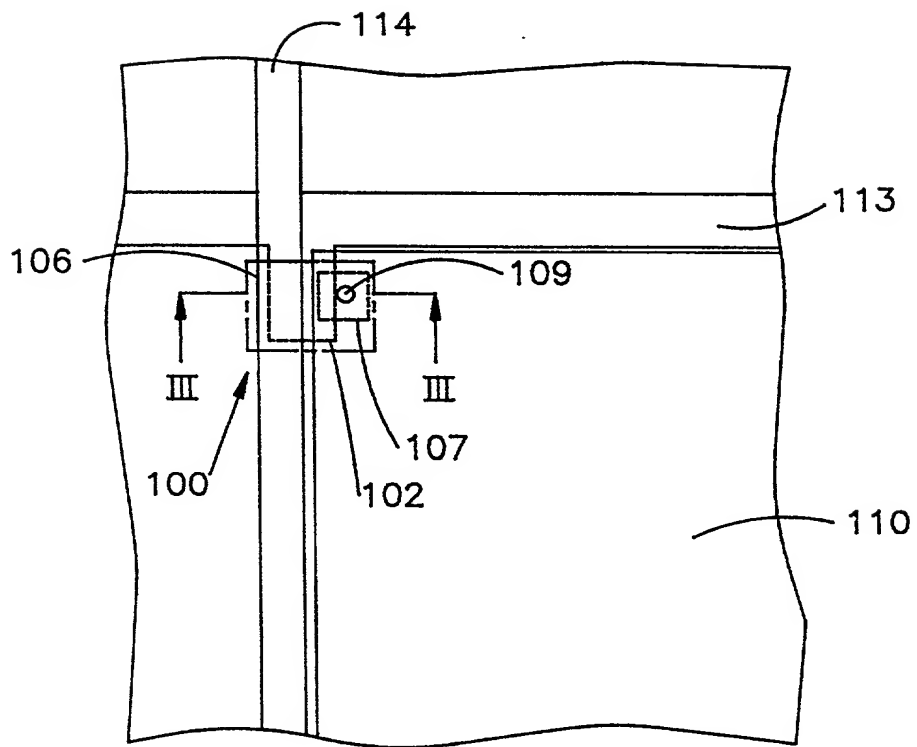


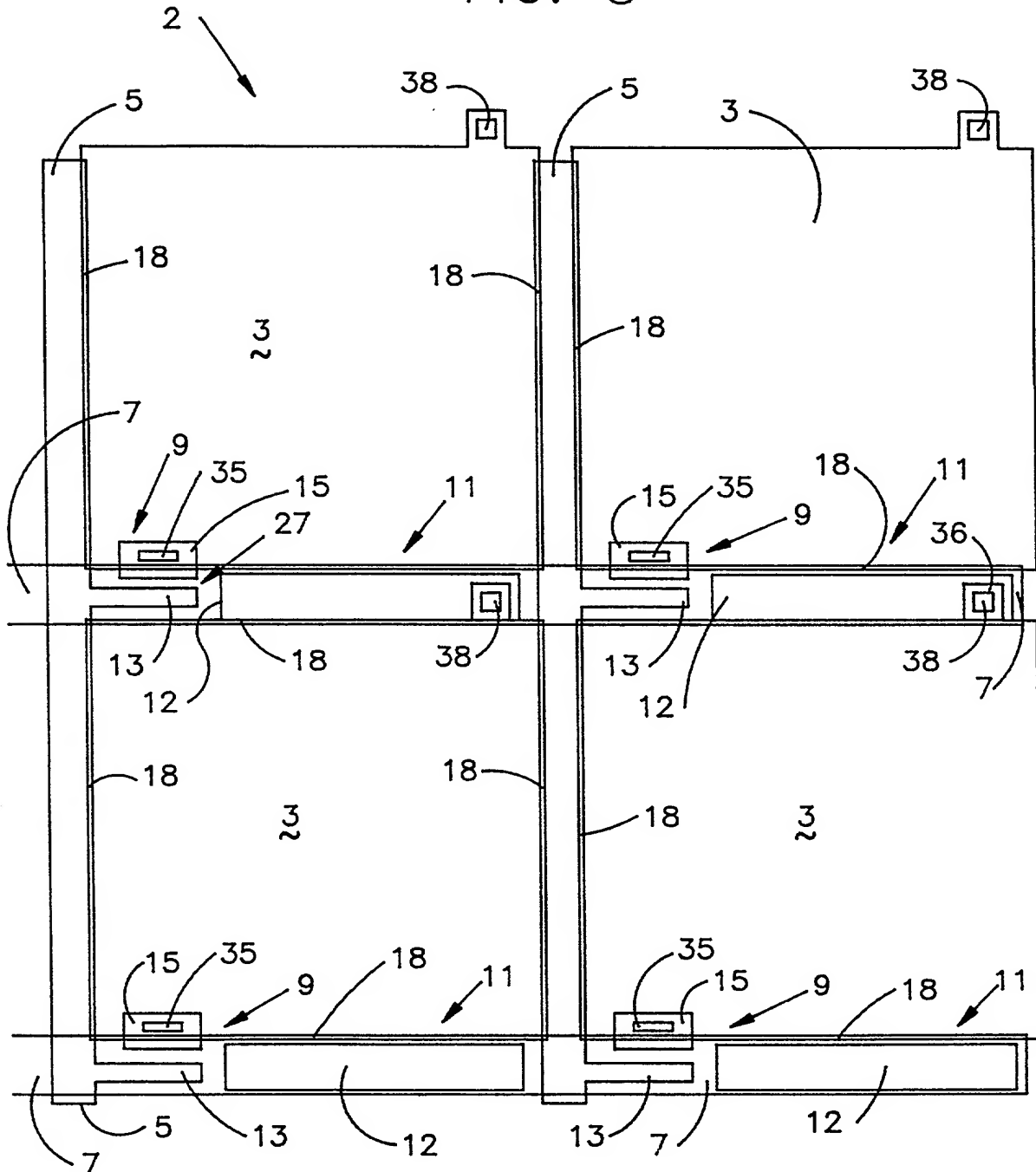
FIG. 2
(Prior Art)

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FIG. 3



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FIG. 4

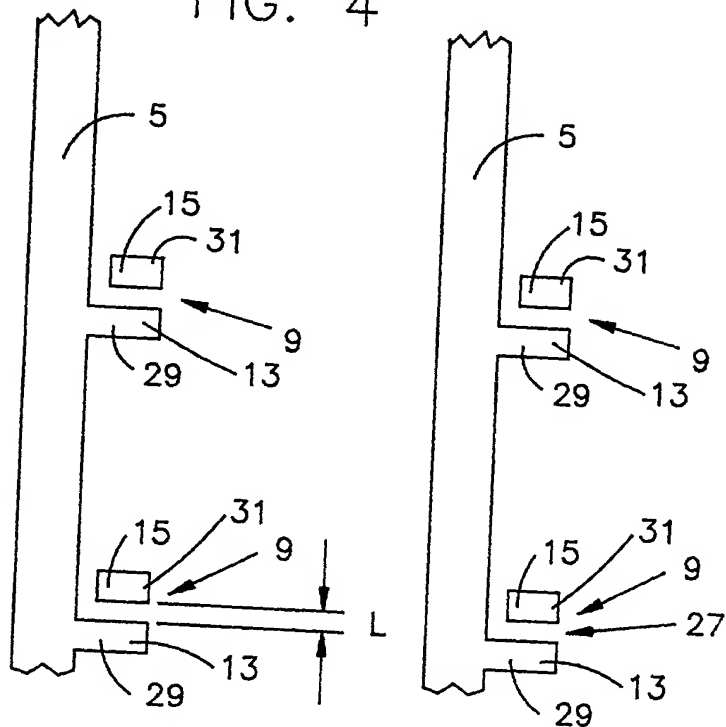


FIG. 5

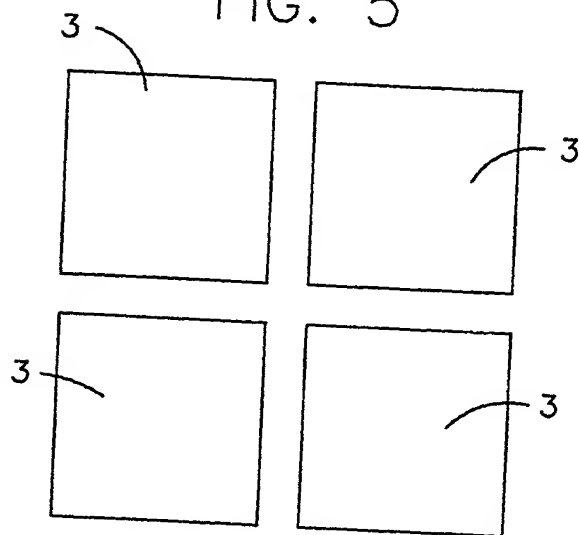


Fig. 1 is a cross-sectional view of a semiconductor device. It shows a substrate 19 with a layer 21, a patterned layer 23, a layer 25, a layer 29, and a top layer 33. A central region 7 is defined by a trench 35 and a structure 17. Other features include 9, 13, 15, 27, and 31.

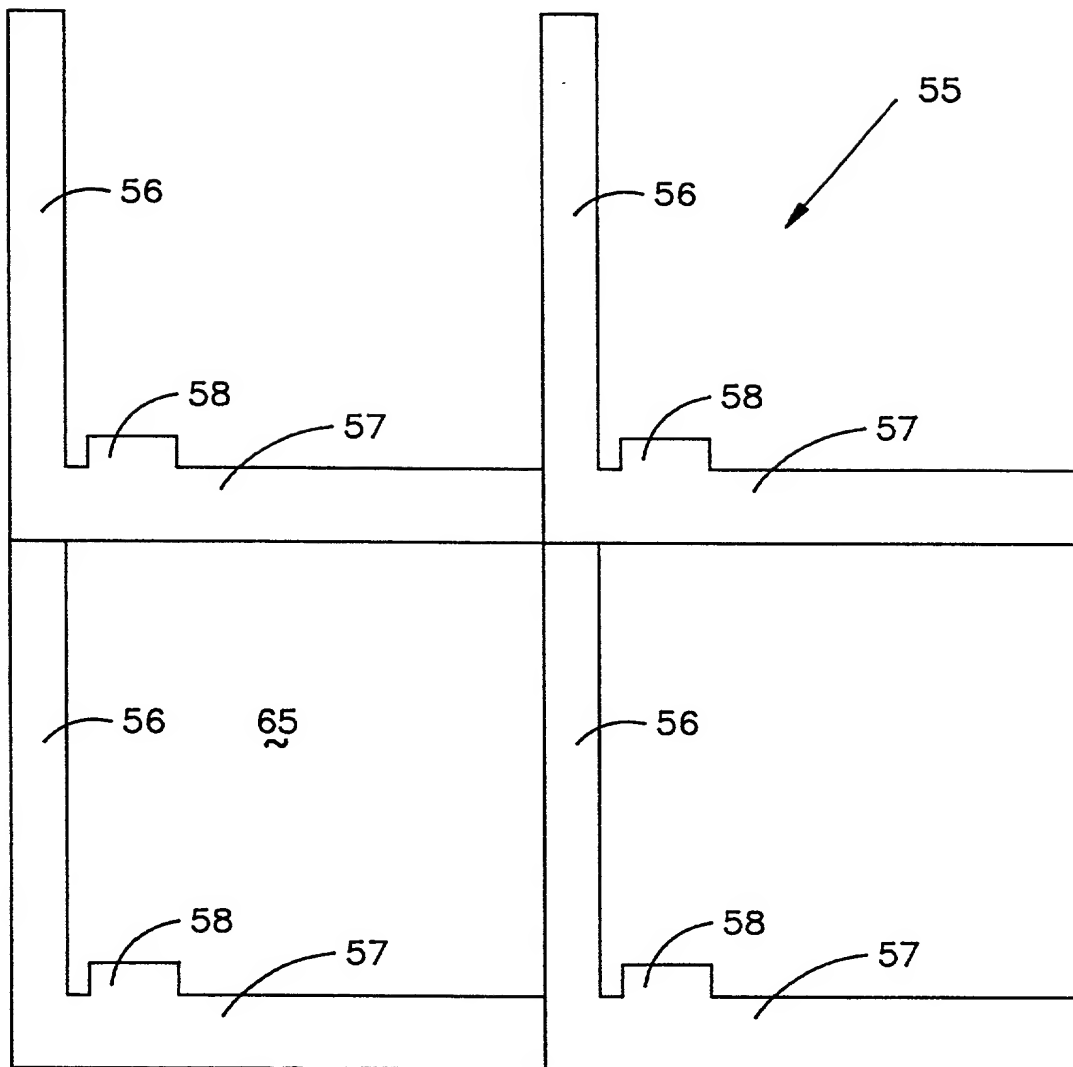


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FIG. 8



20020129/25001

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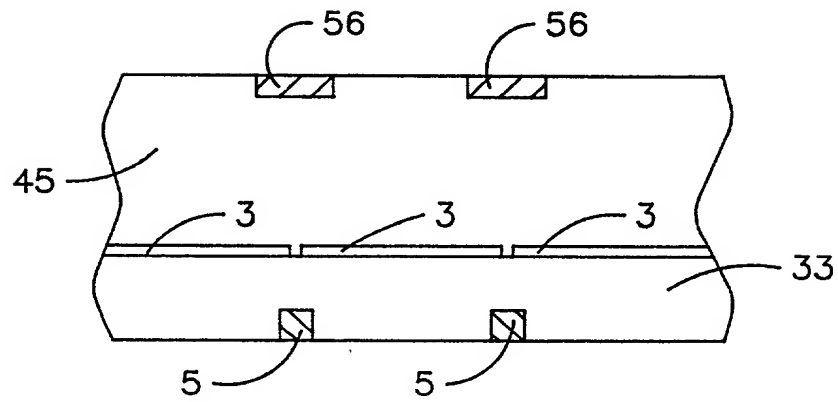


FIG. 9

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